REVISIONS			
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Add vendor CAGE F8859. Add device class V criteria. Correct data limits in paragraph 1.3. Add case outline X. Add table III, delta limits. Update boilerplate to MIL-PRF-38535 requirements jak.	01-07-27	Thomas M. Hess
B	Update boilerplate paragraphs to the current MIL-PRF-38535 requirements. - LTG	09-05-01	Thomas M. Hess

REV																				
SHEET																				
REV	B	B																		
SHEET	15	16																		

REV STATUS	REV	B	B	B	B	B	B	B	B	B	B	B	B	B	B
OF SHEETS	SHEET	1	2	3	4	5	6	7	8	9	10	11	12	13	14

PMIC N/A

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DRAWING APPROVAL DATE
89-02-06

REVISION LEVEL
B

DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43218-3990
http://www.dscc.dla.mil

STANDARD MICROCIRCUIT DRAWING

THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE

AMSC N/A

MICROCIRCUIT, DIGITAL, ADVANCED CMOS, DUAL J-$\overline{K}$ POSITIVE EDGE-TRIGGERED FLIP-FLOP, MONOLITHIC SILICON

SIZE	CAGE CODE	
A	**67268**	**5962-89551**

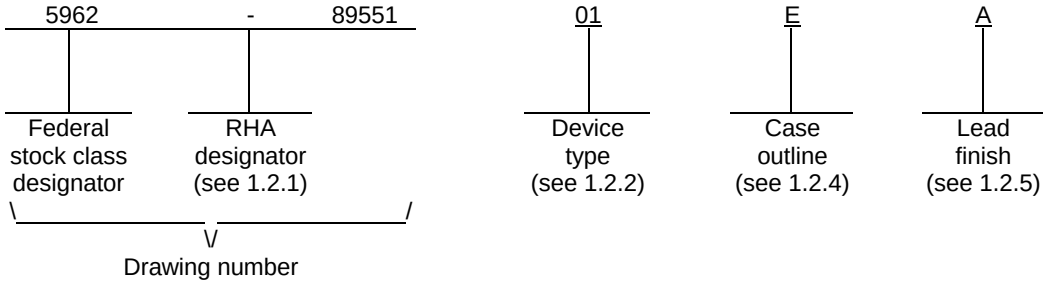
SHEET 1 OF 16

1. SCOPE

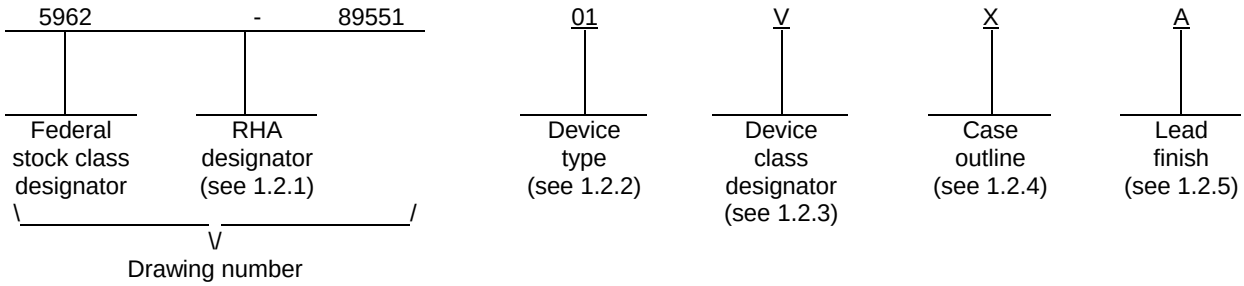
1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following examples.

For device classes M and Q:



For device class V:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54AC109	Dual J-$\overline{K}$ positive edge-triggered flip-flop

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as listed below. Since the device class designator has been added after the original issuance of this drawing, device classes M and Q designators will not be included in the PIN and will not be marked on the device.

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
E	GDIP1-T16 or CDIP2-T16	16	Dual-in-line
F	GDFP2-F16 or CDFP3-F16	16	Flat pack
X	CDFP4-F16	16	Flat pack
2	CQCC1-N20	20	Square leadless chip carrier

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

1.3 Absolute maximum ratings. 1/ 2/ 3/

Supply voltage range (V_{CC}) ..... -0.5 V dc to +7.0 V dc
DC input voltage range (V_{IN}) ..... -0.5 V dc to V_{CC} +0.5 V dc
DC output voltage range (V_{OUT}) ..... -0.5 V dc to V_{CC} +0.5 V dc
Input clamp current (I_{IK}) (V_{IN} < 0.0 to V_{IN} > V_{CC})..... ±20 mA
Output clamp current (I_{OK}) (V_{OUT} < 0.0 to V_{OUT} > V_{CC}) ..... ±20 mA
Continuous output current (I_{OUT}) (V_{OUT} = 0.0 to V_{CC})..... ±25 mA
Continuous current through V_{CC} or GND..... ±50 mA
Storage temperature range (T_{STG}) ..... -65°C to +150°C
Maximum power dissipation (P_D): ..... 500 mW
Lead temperature (soldering, 10 seconds)..... +260°C
Thermal resistance, junction-to-case (θ_{JC}) ..... See MIL-STD-1835
Junction temperature (T_J) ..... +175°C

1.4 Recommended operating conditions. 2/

Supply voltage range (V_{CC}) ..... +3.0 V dc to +6.0 V dc 4/
Case operating temperature range (T_C) ..... -55°C to +125°C
Input voltage range (V_{IN}) ..... 0.0 V dc to V_{CC}
Output voltage range (V_{OUT})..... 0.0 V dc to V_{CC}
Input rise or fall time (t_r, t_f):
V_{CC} = 3.6 V to 5.5 V ..... 0 to 8.0 ns/V
Minimum setup time, Jn, $\overline{Kn}$, to CPn (t_s):
T_C = +25°C, V_{CC} = 3.0 V ..... 6.5 ns
T_C = +25°C, V_{CC} = 4.5 V ..... 4.5 ns
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 8.0 ns
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 5.5 ns
Minimum hold time, Jn or $\overline{Kn}$ to CPn (t_h):
T_C = +25°C, V_{CC} = 3.0 V ..... 0.0 ns
T_C = +25°C, V_{CC} = 4.5 V ..... 0.5 ns
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 0.0 ns
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 0.5 ns
Minimum pulse width CPn, (t_w):
T_C = +25°C, V_{CC} = 3.0 V ..... 5.0 ns
T_C = +25°C, V_{CC} = 4.5 V ..... 5.0 ns
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 5.5 ns
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 5.0 ns
Minimum pulse width $\overline{CDn}$ or $\overline{SDn}$, (t_w):
T_C = +25°C, V_{CC} = 3.0 V ..... 6.0 ns
T_C = +25°C, V_{CC} = 4.5 V ..... 5.0 ns
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 8.0 ns
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 5.5 ns
Minimum recovery time $\overline{CDn}$, $\overline{SDn}$ to CPn (t_{rec}):
T_C = +25°C, V_{CC} = 3.0 V ..... 0.5 ns
T_C = +25°C, V_{CC} = 4.5 V ..... 0.5 ns
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 0.5 ns
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 0.5 ns
Maximum frequency CPn, (f_{MAX}):
T_C = +25°C, V_{CC} = 3.0 V ..... 85 MHz
T_C = +25°C, V_{CC} = 4.5 V ..... 95 MHz
T_C = -55°C to +125°C, V_{CC} = 3.0 V ..... 65 MHz
T_C = -55°C to +125°C, V_{CC} = 4.5 V ..... 95 MHz

1/ Unless otherwise noted, all voltages are referenced to GND.
2/ The limits for the parameters specified herein shall apply over the full specified V_{CC} range and case temperature range of -55°C to +125°C.
3/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.
4/ Operation from 2.0 V dc to 3.0 V dc is provided for compatibility with data retention and battery backup systems. Data retention implied no input transitions and no stored data loss with the following condition: $V_{IH} \geq 70$ percent V_{CC}, $V_{IL} \leq 30$ percent V_{CC}, $V_{OH} \geq 70$ percent V_{CC} at –20 μA, $V_{OL} \leq 30$ percent V_{CC} at 20 μA.

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents cited in the solicitation or contract.

ELECTRONIC INDUSTRIES ALLIANCE (EIA)

JEDEC Standard No. 20 - Standard for Description of 54/74ACXXXXX and 54/74ACTXXXXX Advanced High-Speed CMOS Devices.

(Copies of these documents are available online at http://www.jedec.org or from Electronic Industries Alliance, 2500 Wilson Boulevard, Arlington, VA 22201-3834).

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.

3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified in figure 4.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.

3.9 Verification and review for device class M. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 38 (see MIL-PRF-38535, appendix A).

TABLE I. Electrical performance characteristics.

Test and MIL-STD-883 test method 1/	Symbol	Test conditions 2/ $-55°C \le T_C \le +125°C$ $+3.0\ V \le V_{CC} \le +5.5\ V$ unless otherwise specified	Device type and device class	V_{CC}	Group A subgroups	Limits 3/		Unit
						Min	Max	
Positive input clamp voltage 3022	V_{IC+}	For input under test I_{IN} = 1.0 mA	V All	0.0 V	1	0.4	1.5	V
Negative input clamp voltage 3022	V_{IC-}	For input under test I_{IN} = -1.0 mA	V All	Open	1	-0.4	-1.5	V
High level output voltage 3006	V_{OH} 4/	V_{IN} = V_{IH} minimum or V_{IL} maximum I_{OH} = -50 µA	All All	3.0 V	1, 2, 3	2.9		V
				4.5 V	1, 2, 3	4.4		
				5.5 V	1, 2, 3	5.4		
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OH} = -12 mA	All All	3.0 V	1, 2, 3	2.40		
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OH} = -24 mA	All All	4.5 V	1, 2, 3	3.70		
				5.5 V	1, 2, 3	4.70		
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OH} = -50 mA	All All	5.5 V	1, 2, 3	3.85		
Low level output voltage 3007	V_{OL} 4/	V_{IN} = V_{IH} minimum or V_{IL} maximum I_{OL} = 50 µA	All All	3.0 V	1, 2, 3		0.1	V
				4.5 V	1, 2, 3		0.1	
				5.5 V	1, 2, 3		0.1	
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OL} = 12 mA	All All	3.0 V	1, 2, 3		0.50	
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OL} = 24 mA	All All	4.5 V	1, 2, 3		0.50	
				5.5 V	1, 2, 3		0.50	
		V_{IN} = V_{IH} minimum or V_{IL} maximum, I_{OL} = 50 mA	All All	5.5 V	1, 2, 3		1.65	
High level input voltage	V_{IH} 5/		All All	3.0 V	1, 2, 3	2.1		V
				4.5 V	1, 2, 3	3.15		
				5.5 V	1, 2, 3	3.85		
Low level input voltage	V_{IL} 5/		All All	3.0 V	1, 2, 3		0.9	V
				4.5 V	1, 2, 3		1.35	
				5.5 V	1, 2, 3		1.65	
Input leakage current low 3010	I_{IL}	V_{IN} = 0.0 V	All All	5.5 V	1, 2, 3		-1.0	µA
Input leakage current high 3009	I_{IH}	V_{IN} = 5.5 V	All All	5.5 V	1, 2, 3		1.0	µA
Quiescent supply current, output high 3005	I_{CCH}	V_{IN} = V_{CC} or GND	All All	5.5 V	1, 2, 3		80	µA
Quiescent supply current, output low 3005	I_{CCL}	V_{IN} = V_{CC} or GND	All All	5.5 V	1, 2, 3		80	µA

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test and MIL-STD-883 test method 1/	Symbol	Test conditions 2/ $-55°C \le T_C \le +125°C$ $+3.0\ V \le V_{CC} \le +5.5\ V$ unless otherwise specified	Device type and device class	V_{CC}	Group A subgroups	Limits 3/		Unit
						Min	Max	
Input capacitance 3012	C_{IN}	See 4.4.1c $T_C = +25°C$	All All		4		8.0	pF
Power dissipation capacitance	C_{PD} 6/	See 4.4.1c $T_C = +25°C$	All All	5.0 V	4		50.0	pF
Functional tests 3014		Tested at $V_{CC} = 3.0$ V and repeated at $V_{CC} = 5.5$ V See 4.4.1b	All All	3.0 V 5.5 V	7, 8 7, 8	L L	H H	
Propagation delay time, CPn to Qn or $\overline{Q}$n 3003	t_{PHL1} 7/	$C_L = 50$ pF minimum $R_L = 500\Omega$ See figure 4	All All	3.0 V	9 10, 11	1.0 1.0	11.0 13.5	ns
				4.5 V	9 10, 11	1.0 1.0	8.5 10.0	
	t_{PLH1} 7/			3.0 V	9 10, 11	1.0 1.0	13.5 17.5	
				4.5 V	9 10, 11	1.0 1.0	10.0 12.0	
Propagation delay time, $\overline{CD}$n or $\overline{SD}$n to Qn or $\overline{Q}$n 3003	t_{PHL2} 7/	$C_L = 50$ pF minimum $R_L = 500\Omega$ See figure 4	All All	3.0 V	9 10, 11	1.0 1.0	12.0 14.0	ns
				4.5 V	9 10, 11	1.0 1.0	9.5 10.5	
	t_{PLH2} 7/			3.0 V	9 10, 11	1.0 1.0	11.0 13.0	
				4.5 V	9 10, 11	1.0 1.0	9.0 9.5	

1/ For tests not listed in the referenced MIL-STD-883, (V_{IH}, V_{IL}), utilize the general test procedure under the conditions listed herein.

2/ Each input/output, as applicable shall be tested at the specified temperature for the specified limits. Output terminals not designated shall be high level logic, low level logic, or open, except as follows:

a. V_{IC} (pos) tests, the GND terminal can be open. $T_C = +25°C$.
b. V_{IC} (neg) tests, the V_{CC} terminal shall be open. $T_C = +25°C$.
c. All I_{CC} tests, the output terminal shall be open. When performing these tests, the current meter shall be placed in the circuit such that all current flows through the meter.

Additional detailed information on qualified devices (i.e. pin for pin conditions and testing sequence) is available from the qualifying activity (DSCC-VQC) upon request.

3/ For negative and positive voltage and current values, the sign designates the potential difference in reference to GND and the direction of current flow, respectively; and the absolute value of the magnitude, not the sign, is relative to the minimum and maximum limits, as applicable, listed herein. All devices shall meet or exceed the limits specified in table I, as applicable, at $3.0\ V \le V_{CC} \le 3.6$ V and $4.5\ V \le V_{CC} \le 5.5$ V.

TABLE I. Electrical performance characteristics - Continued.

4/ V_{OH} and V_{OL} tests will be tested at V_{CC} = 3.0 V and V_{CC} = 4.5 V. V_{OH} and V_{OL} are guaranteed, if not tested, for other values of V_{CC}. Limits shown apply to operation at V_{CC} = 3.3 V ±0.3 V and V_{CC} = 5.0 V ±0.5 V. Transmission driving tests are performed at V_{CC} = 5.5 V with a 2 millisecond duration maximum.

5/ V_{IH} and V_{IL} tests are guaranteed if applied as a forcing function for V_{OH} and V_{OL} tests.

6/ Power dissipation capacitance (C_{PD}), determines the dynamic power consumption, $P_D = (C_{PD} + C_L)(V_{CC} \times V_{CC})f + I_{CC}(V_{CC})$, and the dynamic current consumption (I_S) is, $I_S = (C_{PD} + C_L)V_{CC}f + I_{CC}$.

7/ AC limits at 5.5 V V_{CC} are equal to limits at 4.5 V V_{CC} and guaranteed by testing at 4.5 V V_{CC}. Minimum ac is guaranteed for 5.5 V V_{CC} by guardbanding the 4.5 V V_{CC} limits to 1.5 ns (minimum).

Device type	01	
Case outlines	E, F, and X	2
Terminal number	Terminal symbol	Terminal symbol
1	$\overline{CD}1$	NC
2	J1	$\overline{CD}1$
3	$\overline{K}1$	J1
4	CP1	$\overline{K}1$
5	$\overline{SD}1$	CP1
6	Q1	NC
7	$\overline{Q}1$	$\overline{SD}1$
8	GND	Q1
9	$\overline{Q}2$	$\overline{Q}1$
10	Q2	GND
11	$\overline{SD}2$	NC
12	CP2	$\overline{Q}2$
13	$\overline{K}2$	Q2
14	J2	$\overline{SD}2$
15	$\overline{CD}2$	CP2
16	V_{CC}	NC
17		$\overline{K}2$
18		J2
19		$\overline{CD}2$
20		V_{CC}

NC = No connection.

FIGURE 1. Terminal connections.

Inputs					Outputs	
$\overline{SD}n$	$\overline{CD}n$	CPn	Jn	$\overline{K}n$	Qn	$\overline{Q}n$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H	H
H	H	↑	L	L	L	H
H	H	↑	H	L	Toggle	Toggle
H	H	↑	L	H	Q0	$\overline{Q}0$
H	H	↑	H	H	H	L
H	H	L	X	X	Q0	$\overline{Q}0$

H = High voltage level
L = Low voltage level
X = Irrelevant
↑ = Low-to-high clock transition
Q0($\overline{Q}0$) = Previous Q0 ($\overline{Q}0$) before low-to-high transition of the clock.

FIGURE 2. Truth table.

(Each flip-flop)

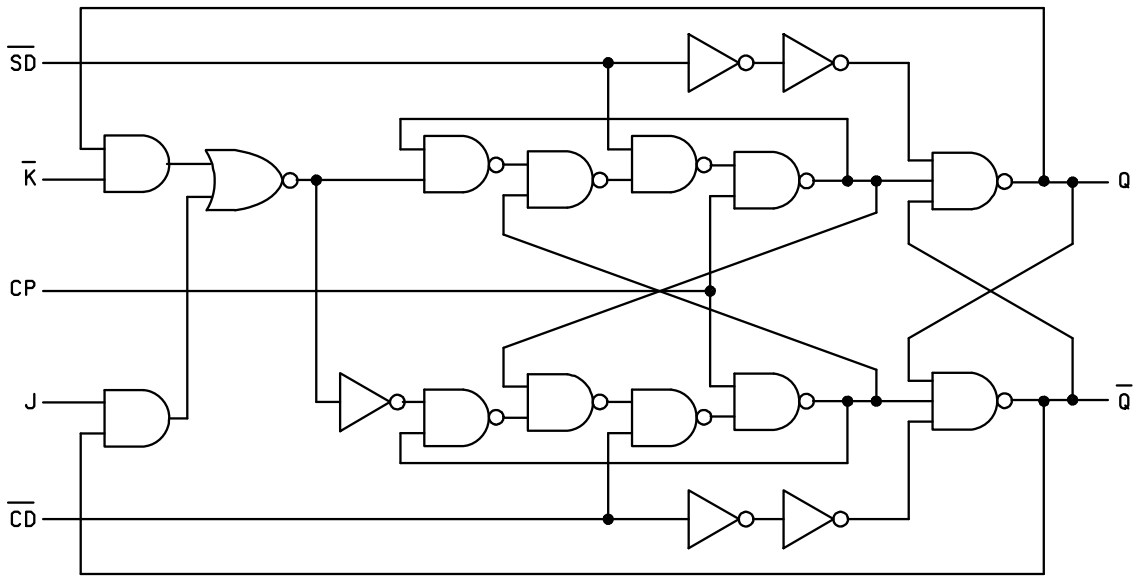


FIGURE 3. Logic diagram.

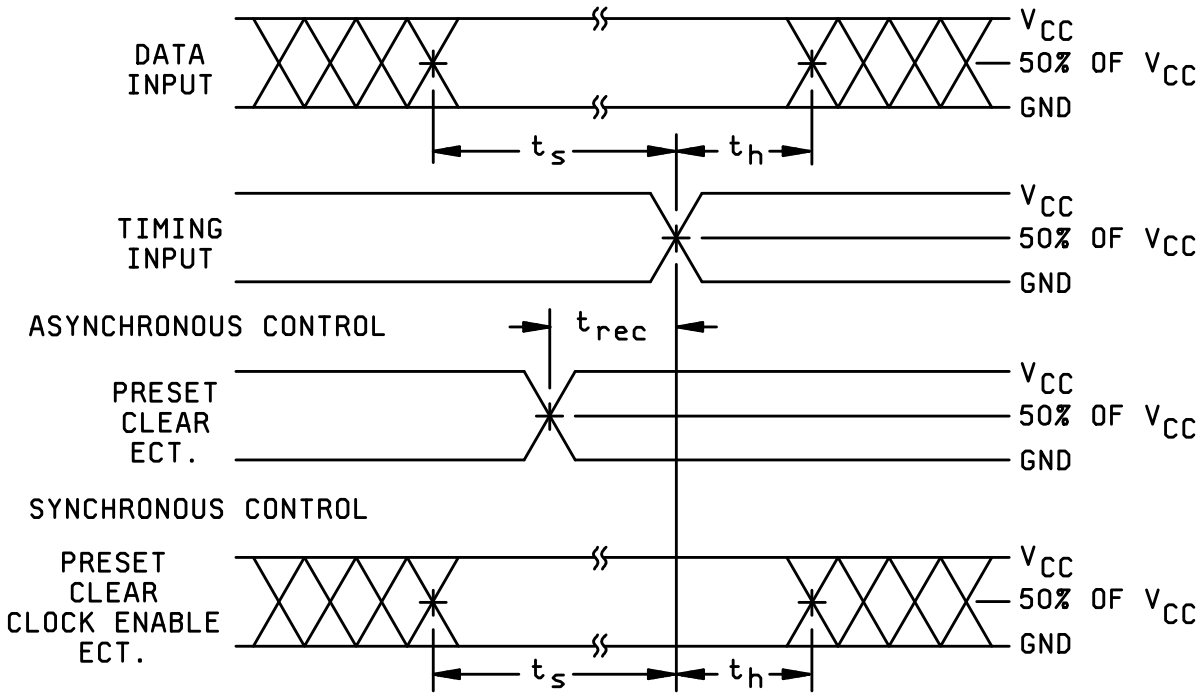


FIGURE 4. Switching waveforms and test circuit.

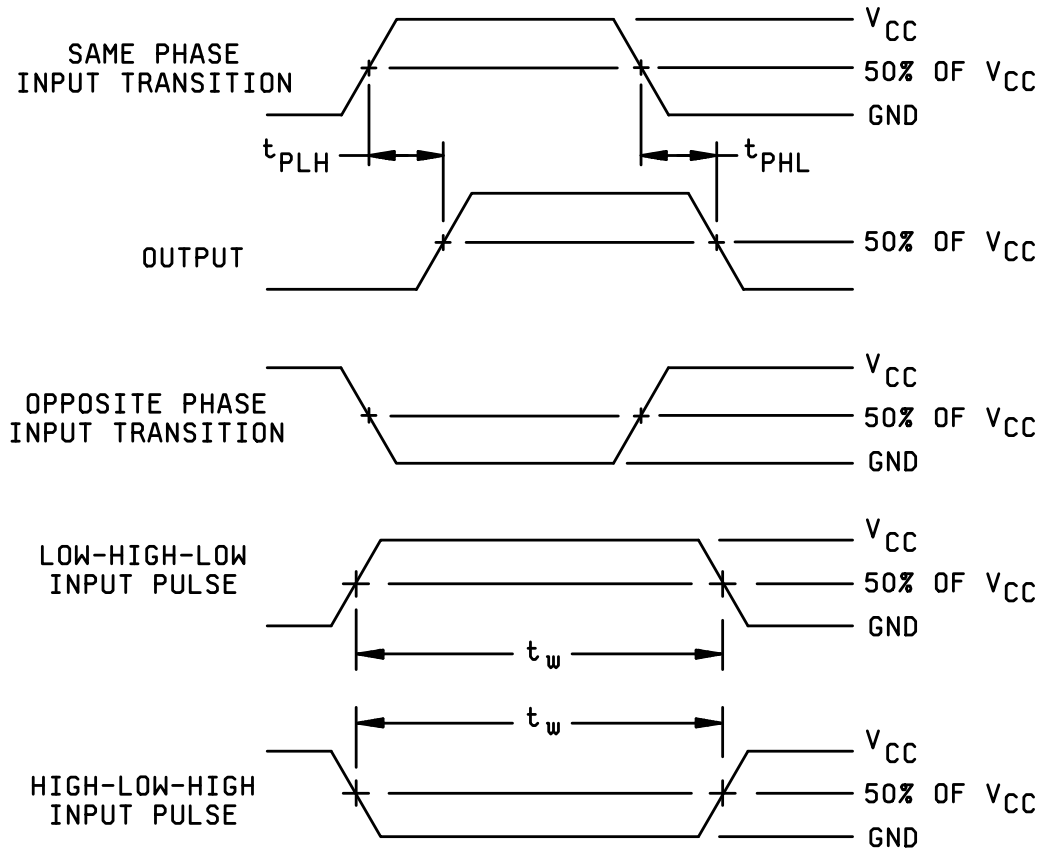
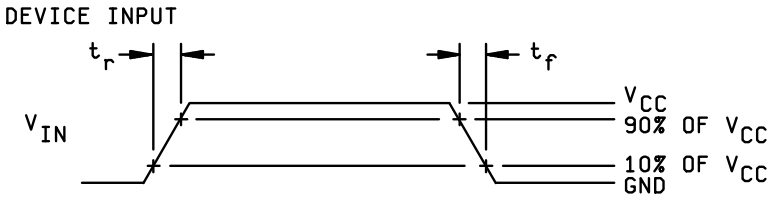
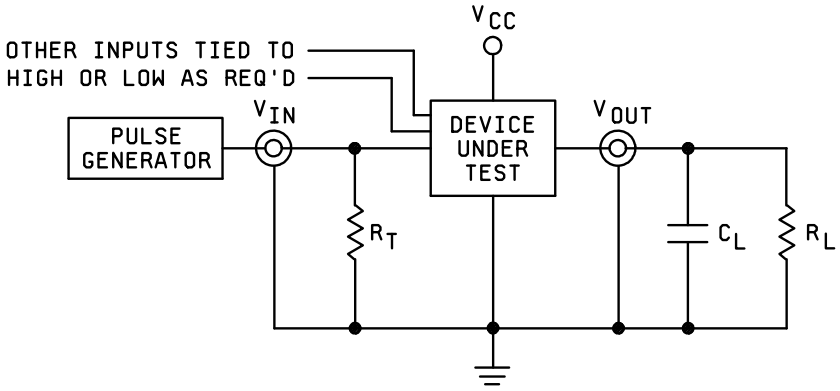


FIGURE 4. Switching waveforms and test circuit - Continued.





NOTES:
1. C_L = 50 pF minimum or equivalent (includes test jig and probe capacitance).
2. R_T = 50Ω or equivalent, R_L = 500Ω or equivalent.
3. Input rise and fall times; t_r = 3.0 ns, t_f = 3.0 ns
4. Outputs must be switching from 10% V_{CC} to 90% V_{CC} in accordance with the device truth table. For f_{max} input duty cycle = 50%

FIGURE 4. Switching waveforms and test circuit - Continued.

4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.

(2) T_A = +125°C, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

b. Interim and final electrical test parameters shall be as specified in table II herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table in figure 2 herein. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2, herein. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.

c. C_{IN} shall be measured only for initial qualification and after process or design changes which may affect capacitance. C_{IN} shall be measured between the designated terminal and GND at a frequency of 1 MHz. C_{PD} shall be tested in accordance with the latest revision of JEDEC Standard No. 20 and table I herein. For C_{IN} and C_{PD}, test all applicable pins on five devices with zero failures.

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	- - -	- - -	1
Final electrical parameters (see 4.2)	1, 2, 3, 7, 8, 9 1/	1/ 1, 2, 3, 7, 8, 9, 10, 11	2/ 3/ 1, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	3/ 1, 2, 3, 7,8, 9, 10, 11
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9	1, 7, 9

1/ PDA applies to subgroup 1.
2/ PDA applies to subgroups 1, 7 and deltas.
3/ Delta limits as specified in table III, shall be required where specified and the delta limits shall be completed with reference to the zero hour electrical parameters

TABLE III. Burn-in and operating life test, delta parameters (+25°C). 1/

Parameter	Symbol	Delta limits
Quiescent current	I_{CC}	±300 nA
Input current low level	I_{IL}	±20 nA
Input current high level	I_{IH}	±20 nA
Output voltage low level (I_{OL} = 24 mA, V_{CC} = 5.5 V)	V_{OL}	±0.04 V
Output voltage high level (I_{OH} = -24 mA, V_{CC} = 5.5 V)	V_{OH}	±0.20 V

1/ This table is a representation of what vendor CAGE F8859 has experienced and is guaranteed and not meant to be construed as a quality assurance requirement for any other vendor.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

a. Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

b. T_A = +125°C, minimum.

c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

a. End-point electrical parameters shall be as specified in table II herein.

b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25°C ±5°C, after exposure, to the subgroups specified in table II herein.

4.5 Methods of inspection. Methods of inspection shall be specified as follows:

4.5.1 Voltage and current. Unless otherwise specified, all voltages given are referenced to the microcircuit GND terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.4 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 09-05-01

Approved sources of supply for SMD 5962-89551 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN 1/	Vendor CAGE number	Vendor similar PIN 2/
5962-8955101EA	0C7V7	54AC109DMQB
5962-8955101FA	0C7V7	54AC109FMQB
5962-8955101XA	3/	54AC109K02Q
5962-8955101XC	3/	54AC109K01Q
5962-89551012A	0C7V7	54AC109LMQB
5962-8955101VXA	3/	54AC109K02V
5962-8955101VXC	3/	54AC109K01V

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
3/ Not available from an approved source of supply.

Vendor CAGE number	Vendor name and address
0C7V7	QP Semiconductor 2945 Oakmead Village Court Santa Clara, CA 95051

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.